



2025 MPW schedule

Last updated: February 26, 2025

MPW name	Fab	Processes	Tape-In	Ship Date
PH18DA - B5614	NPB - Fab 3	SiPho 0.18um	8-20-24	8-7-25
PH18M* - B5617	NPB - Fab 3	SiPho 0.18um	9-10-24	5-5-25
SB*18 - B5619	NPB - Fab 3	SiGe BiCMOS 0.18um	10-08-24	4-28-25
CS18* - B5616	MH - Fab 2	CMOS-SOI 0.18um	10-29-24	
CA18 - B5621	NPB - Fab 3	RFCMOS 0.18um	11-05-24	4-29-25
SB*18 - B5622	NPB - Fab 3	SiGe BiCMOS 0.18um	11-19-24	6-20-25
SB*18 - B6000	NPB - Fab 3	SiGe BiCMOS 0.18um	1-14-25	8-27-25
Q1 2025	NM - Fab 11	TPS65MSPM	2-04-25	
CA18 - B6002	NPB - Fab 3	RFCMOS 0.18um	2-11-25	8-21-25
32nd MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	2-25-25	
PH18M* - B6003	NPB - Fab 3	SiPho 0.18um	2-25-25	10-20-25
1 st MPW RFSOI-RSM5T	TSIT - Fab 10	90RSC/65RSA2/65RSB2/65RSC	3-10-25	
34th MPW - Uozu, Japan	TPSCo - Fab 7	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMK/MSA/MSB/MSK, TPS65RF, TPS65SG	3-24-25	
PH18DA - B6006	NPB - Fab 3	SiPho 0.18um	3-25-25	3-12-26
SB*18 - B6007	TJT - Fab 9	SiGe BiCMOS 0.18um	4-08-25	
SH125T18APRIL	MH - Fab 2	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	4-10-25 4-17-25	
35th MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	4-14-25	
SBC18HE5PCA - B6008	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	4-22-25	
CA18 - B6009	NPB - Fab 3	RFCMOS 0.18um	5-06-25	11-13-25
Q2 2025	NM - Fab 11	TPS65MSPM	5-15-25	
PH18M* - B6010	NPB - Fab 3	SiPho 0.18um	5-20-25	1-12-26
33rd MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	5-26-25	
SB*18 - B6011	NPB - Fab 3	SiGe BiCMOS 0.18um	6-03-25	12-22-25
CS18* - B6012	MH - Fab 2	CMOS-SOI 0.18um	6-17-25	
SB*/CA13* - B6013	NPB - Fab 3	SiGe BiCMOS/RF CMOS 0.13um	7-01-25	3-3-26
SBC18HE5PCA - B6014	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	7-15-25	
SB*18 - B6015	NPB - Fab 3	SiGe BiCMOS 0.18um	7-29-25	2-16-26
PH18DA - B6016	NPB - Fab 3	SiPho 0.18um	8-12-25	7-30-26

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Q3 2025	NM - Fab 11	TPS65MSPM	8-15-25	
34th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	8-25-25	
CA18 - B6017	NPB - Fab 3	RFCMOS 0.18um	8-26-25	2-06-26
2nd MPW RFSOI-RSS5T	TSIT - Fab 10	90RSC/65RSA2/65RSB2/65RSC	9-8-25	
PH18M* - B6019	NPB - Fab 3	SiPho 0.18um	9-23-25	5-18-26
36th MPW - Uozu, Japan	TPSCo - Fab 7	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMK/MSA/MSB/MSK, TPS65RF, TPS65SG	9-29-25	
SB*18 - B6020	NPB - Fab 3	SiGe BiCMOS 0.18um	10-07-25	4-16-26
SBC18HE5PCA - B6021	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	10-21-25	
37th MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	10-27-25	
PH18M* - B6022	NPB - Fab 3	SiPho 0.18um	10-28-25	6-22-26
Q4 2025	NM - Fab 11	TPS65MSPM	11-14-25	
SH225T18NOV	MH - Fab 2	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	11-17-25 11-23-25	
35th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	11-25-25	
CS18* - B6023	MH - Fab 2	CMOS-SOI 0.18um	1-6-26	

Notes: "Shuttles" (SH*) are run at Fab 2

* 0.13u MH – fab 2 Shuttle / MPW slots will be considered per needs

Please contact your customer account manager for additional information.

Fab2 - Tower Semiconductor 200mm wafer fabrication facility at Migdal Ha'emek, Israel

Fab3 - Tower Semiconductor 200mm wafer fabrication facility at Newport Beach, CA

Fab5 - Tower Semiconductor 200mm wafer fabrication facility at Tonami, Japan

Fab7 - Tower Semiconductor 300mm wafer fabrication facility at Uozu, Japan

Fab9 - Tower Semiconductor 200mm wafer fabrication facility at San Antonio, TX

Fab10 - Tower Semiconductor 300mm wafer fabrication facility at Agrate, Italy

Fab11 - Tower Semiconductor 300mm wafer fabrication facility at Rio Rancho, NM